## Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **General Description**

The MAX14434-MAX14436 are fast, low-power, 4-channel digital galvanic isolators using Maxim's proprietary process technology. These devices transfer digital signals between circuits with different power domains while using as little as 0.58mW per channel at 1Mbps with a 1.8V supply. The MAX14434/5/6 have an isolation rating of 5kV<sub>RMS</sub> for 60 seconds. For applications requiring 3kV<sub>RMS</sub> or 3.75kV<sub>RMS</sub> of isolation, see the MAX14430-MAX14432.

The MAX14434–MAX14436 family offers all three possible unidirectional channel configurations to accommodate any 4-channel design, including SPI, RS-232, RS-485, and digital I/O applications. Output enable for the A side of the MAX14435R/S/U/V is active-low, making them ideal for isolating a port on a shared SPI bus since the CS signal can directly enable the MISO signal on the isolator. All other devices in the family have the traditional active-high enable.

Devices are available with a maximum data rate of either 25Mbps or 200Mbps and with outputs that are either default-high or default-low. The default is the state the output assumes when the input is either not powered or is open-circuit. See the <u>Ordering Information</u> and <u>Product</u> <u>Selector Guide</u> for suffixes associated with each option. Independent 1.71V to 5.5V supplies on each side of the isolator also make the devices suitable for use as level translators.

The MAX14434–MAX14436 are available in a 16-pin widebody SOIC package with 8mm of creepage and clearance. The package material has a minimum comparative tracking index (CTI) of 600V, which gives it a group I rating in creepage tables. All devices are rated for operation at ambient temperatures of -40°C to +125°C.

#### **Benefits and Features**

- Robust Galvanic Isolation for Fast Digital Signals
  - 200Mbps Data Rate
  - Withstands 5kV<sub>RMS</sub> for 60s (V<sub>ISO</sub>)
  - Continuously Withstands 848V<sub>RMS</sub> (VIOWM)
  - Withstands ±10kV Surge between GNDA and GNDB with 1.2/50µs waveform
  - High CMTI (50kV/µs, Typical)
- Low Power Consumption
  - 1.1mW per Channel at 1Mbps with V<sub>DD</sub> = 3.3V
  - 3.5mW per Channel at 100Mbps with V<sub>DD</sub> = 1.8V
- Options to Support a Broad Range of Applications
  - 2 Data Rates (25Mbps, 200Mbps)
  - 3 Channel Direction Configurations
  - 2 Output Default States (High/Low)

#### **Applications**

- Isolated SPI Interface
- Fieldbus Communications for Industrial Automation
- Isolated RS-485/RS-422, CAN
- Battery Management
- Medical Systems

#### **Safety Regulatory Approvals**

- UL According to UL1577
- cUL According to CSA Bulletin 5A

Ordering Information and Product Selector Guide appear at end of data sheet.



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#### **Absolute Maximum Ratings**

V <sub>DDA</sub> to GNDA	0.3V to +6V
V <sub>DDB</sub> to GNDB	0.3V to +6V
IN_, EN_ on Side A to GNDA	0.3V to +6V
IN_, EN_ on Side B to GNDB	0.3V to +6V
OUT_ on Side A to GNDA	0.3V to (V <sub>DDA</sub> + 0.3V)
OUT_ on Side B to GNDB	0.3V to (V <sub>DDB</sub> + 0.3V)
Short-Circuit Duration	
OUT_ on Side A to GNDA,	
OUT_ on Side B to GNDB	Continuous

Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
Wide SOIC (derate 14.1mW/°C above +70°C)	1126.8mW
Operating Temperature Range40°C	to +125°C
Maximum Junction Temperature	+150°C
Storage Temperature Range60°C	to +150°C
Soldering Temperature (reflow)	+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **Package Information**

PACKAGE TYPE: 16 WIDE SOIC	
Package Code	W16MS+12
Outline Number	21-0042
Land Pattern Number	90-0107
THERMAL RESISTANCE, FOUR-LAYER BOARD	
Junction to Ambient ( $\theta_{JA}$ )	71°C/W
Junction to Case $(\theta_{JC})$	24°C/W

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

#### **DC Electrical Characteristics**

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15pF, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}) (Note 1)$ 

PARAMETER	SYMBOL	CONDITIONS		TYP	MAX	UNITS
POWER SUPPLY	·					
Supply Voltage	Relative to GNDA	1.71		5.5	V	
Supply voltage	V <sub>DDB</sub>	Relative to GNDB	1.71		5.5	V
Undervoltage-Lockout Threshold	V <sub>UVLO</sub> _	V <sub>DD</sub> _rising	1.5	1.6	1.66	V
Undervoltage-Lockout Threshold Hysteresis	V <sub>UVLO_HYST</sub>			45		mV

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#### **DC Electrical Characteristics (continued)**

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 1)$ 

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
			V <sub>DDA</sub> = 5V		0.52	0.96	
		500kHz square	V <sub>DDA</sub> = 3.3V		0.51	0.93	
		wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		0.50	0.92	
			V <sub>DDA</sub> = 1.8V		0.49	0.64	1
			V <sub>DDA</sub> = 5V		1.63	2.42	1
Supply Current (MAX14434_)		12.5MHz square	V <sub>DDA</sub> = 3.3V		1.59	2.36	
(Note 2)	IDDA	wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		1.58	2.33	mA
			V <sub>DDA</sub> = 1.8V		1.54	2.00	]
			V <sub>DDA</sub> = 5V		4.5	6.14	
		50MHz square	V <sub>DDA</sub> = 3.3V		4.39	6.00	]
		wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		4.35	5.93	]
			V <sub>DDA</sub> = 1.8V		4.21	5.43	
			V <sub>DDB</sub> = 5V		0.87	1.47	
		500kHz square	V <sub>DDB</sub> = 3.3V		0.82	1.41	
		wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		0.81	1.39	- mA - mA
			V <sub>DDB</sub> = 1.8V		0.79	1.32	
	IDDB	12.5MHz square wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 5V		2.97	3.84	
Supply Current (MAX14434_)			V <sub>DDB</sub> = 3.3V		2.00	2.74	
(Note 2)			V <sub>DDB</sub> = 2.5V		1.69	2.36	
			V <sub>DDB</sub> = 1.8V		1.43	2.02	
			V <sub>DDB</sub> = 5V		9.52	11.17	
		50MHz square	V <sub>DDB</sub> = 3.3V		5.68	6.88	
		wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		4.45	5.38	
			V <sub>DDB</sub> = 1.8V		3.46	4.18	
			V <sub>DDA</sub> = 5V		0.62	1.10	
		500kHz square	V <sub>DDA</sub> = 3.3V		0.60	1.06	
		wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		0.59	1.05	
			V <sub>DDA</sub> = 1.8V		0.57	0.83	
			V <sub>DDA</sub> = 5V		1.98	2.80	
Supply Current (MAX14435_)		12.5MHz square	V <sub>DDA</sub> = 3.3V		1.70	2.47	
(Note 2)	I <sub>DDA</sub>	wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		1.61	2.35	mA
			V <sub>DDA</sub> = 1.8V		1.52	2.02	
			V <sub>DDA</sub> = 5V		5.77	7.43	
		50MHz square	V <sub>DDA</sub> = 3.3V		4.73	6.25	-
		wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		4.38	5.81	
			V <sub>DDA</sub> = 1.8V		4.03	5.15	]

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#### **DC Electrical Characteristics (continued)**

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 1)$ 

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
			V <sub>DDB</sub> = 5V		0.78	1.35	
		500kHz square	V <sub>DDB</sub> = 3.3V		0.75	1.30	
		wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		0.74	1.28	
			V <sub>DDB</sub> = 1.8V		0.72	1.16	
			V <sub>DDB</sub> = 5V		2.64	3.49	
Supply Current (MAX14435_)	 	12.5MHz square	V <sub>DDB</sub> = 3.3V		1.90	2.65	]
(Note 2)	IDDB	wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		1.66	2.36	mA
			V <sub>DDB</sub> = 1.8V		1.46	2.03	
			V <sub>DDB</sub> = 5V		8.26	9.91	
		50MHz square	V <sub>DDB</sub> = 3.3V		5.36	6.66	
		wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		4.42	5.52	
			V <sub>DDB</sub> = 1.8V		3.66	4.51	
			V <sub>DDA</sub> = 5V		0.70	1.22	
		500kHz square	V <sub>DDA</sub> = 3.3V		0.67	1.17	
		wave, $C_L = 0pF$	V <sub>DDA</sub> = 2.5V		0.66	1.16	- mA - mA
			V <sub>DDA</sub> = 1.8V		0.64	0.99	
		12.5MHz square wave, C <sub>L</sub> = 0pF 50MHz square	V <sub>DDA</sub> = 5V		2.31	3.15	
	I <sub>DDA</sub>		V <sub>DDA</sub> = 3.3V		1.81	2.56	
			V <sub>DDA</sub> = 2.5V		1.64	2.35	
			V <sub>DDA</sub> = 1.8V		1.50	2.02	
			V <sub>DDA</sub> = 5V		7.04	8.70	
			V <sub>DDA</sub> = 3.3V		5.06	6.46	
		wave, C <sub>L</sub> = 0pF	V <sub>DDA</sub> = 2.5V		4.40	5.67	
Supply Current (MAX14436_)			V <sub>DDA</sub> = 1.8V		3.85	4.83	
(Note 2)			V <sub>DDB</sub> = 5V		0.70	1.24	
		500kHz square	V <sub>DDB</sub> = 3.3V		0.67	1.19	
		wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		0.66	1.17	
			V <sub>DDB</sub> = 1.8V		0.65	1.00	
			V <sub>DDB</sub> = 5V		2.31	3.15	
		12.5MHz square	V <sub>DDB</sub> = 3.3V		1.80	2.57	mA
	IDDB	wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		1.64	2.36	- mA
			V <sub>DDB</sub> = 1.8V		1.49	2.03	
			V <sub>DDB</sub> = 5V		7.01	8.66	
		50MHz square	V <sub>DDB</sub> = 3.3V		5.04	6.46	-
		wave, C <sub>L</sub> = 0pF	V <sub>DDB</sub> = 2.5V		4.40	5.67	
			V <sub>DDB</sub> = 1.8V		3.84	4.83	

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **DC Electrical Characteristics (continued)**

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}) (Note 1)$ 

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
LOGIC INPUTS AND OUTPUTS		1					•
Input High Voltage	Maria	EN_, IN_, relative to GND_	$2.25V \le V_{DD} \le 5.5V$	0.7 x V <sub>DD</sub> _			v
Input High Voltage		EN_, IN_, relative to GND_	1.71V ≤ V <sub>DD</sub> < 2.25V	0.75 x V <sub>DD</sub> _			
	V	EN_, IN_, relative to GND_	$2.25V \le V_{DD} \le 5.5V$			0.8	V
Input Low Voltage	V <sub>IL</sub>	EN_, IN_, relative to GND_	1.71V ≤ V <sub>DD</sub> _ < 2.25V			0.7	
	N	EN_, IN_, relative to GND_	MAX1443_B/E/R/U		410		- mV
Input Hysteresis	V <sub>HYS</sub>	EN_, IN_, relative to GND_	MAX1443_C/F/S/V		80		
Input Pullup Current (Note 3)	I <sub>PU</sub>	IN_, MAX1443_B	S/C/R/S	-10	-5	-1.5	μA
Input Pulldown Current (Note 3)	I <sub>PD</sub>	IN_, MAX1443_E	/F/U/V	1.5	5	10	μA
EN Pullup Current (Note 3)	I <sub>PU_EN</sub>	EN_		-10	-5	-1.5	μA
Input Capacitance	C <sub>IN</sub>	IN_, f <sub>SW</sub> = 1MHz			2		pF
Output Voltage High (Note 3)	V <sub>OH</sub>	V <sub>OUT</sub> _relative to GND_ I <sub>OUT</sub> _= 4mA source		V <sub>DD</sub> _ - 0.4			V
Output Voltage Low (Note 3)	V <sub>OL</sub>	V <sub>OUT</sub> _ relative to I <sub>OUT</sub> _ = 4mA sink				0.4	V

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### Dynamic Characteristics MAX1443\_C/F/S/V

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 3)$ 

PARAMETER	SYMBOL	(	CONDITIONS	MIN	TYP	MAX	UNITS
Common-Mode Transient Immunity	СМТІ	IN_ = GND_	IN_ = GND_ or V <sub>DD</sub> _ (Note 4)		50		kV/µs
Maximum Data Data	00	2.25V ≤ V <sub>DD</sub>	≤ 5.5V	200			Mhra
Maximum Data Rate	DR <sub>MAX</sub>	1.71V ≤ V <sub>DD</sub>	_≤ 1.89V	150			Mbps
Minimum Pulse Width	PW <sub>MIN</sub>	IN_ to	$2.25V \le V_{DD} \le 5.5V$			5	ns
		OUT_	$1.71V \le V_{DD} \le 1.89V$			6.67	
			$4.5V \le V_{DD} \le 5.5V$	4.1	5.4	9.2	
		t <sub>PLH</sub> IN_to OUT_, C <sub>L</sub> = 15pF	$3.0V \le V_{DD} \le 3.6V$	4.2	5.9	10.2	
Propagation Delay (Figure 1)	<sup>t</sup> PLH		2.25V ≤ V <sub>DD</sub> ≤ 2.75V	4.9	7.1	13.4	
			1.71V ≤ V <sub>DD</sub> _ ≤ 1.89V	7.1	10.9	20.3	ns
		IN_to OUT_, C <sub>L</sub> = 15pF	$4.5V \le V_{DD} \le 5.5V$	4.3	5.6	9.4	-
	to		$3.0V \le V_{DD} \le 3.6V$	4.4	6.2	10.5	
			$2.25V \le V_{DD} \le 2.75V$	5.1	7.3	14.1	
			$1.71V \le V_{DD} \le 1.89V$	7.2	10.9	21.7	
Pulse Width Distortion	PWD	t <sub>PLH</sub> -t <sub>PHL</sub>			0.3	2	ns
		$4.5V \le V_{DD}$	≤ 5.5V			3.7	
		3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			4.3	
	<sup>t</sup> SPLH	2.25V ≤ V <sub>DD</sub>	_≤2.75V			6	
Propagation Delay Skew		1.71V ≤ V <sub>DD</sub>	_≤ 1.89V			10.3	ns
Part-to-Part (Same Channel)		4.5V ≤ V <sub>DD</sub> _	≤ 5.5V			3.8	
	+	3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			4.7	
	t <sub>SPHL</sub>	2.25V ≤ V <sub>DD</sub>	≤ 2.75V			6.5	
		1.71V ≤ V <sub>DD</sub>	≤ 1.89V			11.5	
Propagation Delay Skew	t <sub>SCSLH</sub>	1.71V ≤ V <sub>DD</sub>	$1.71V \le V_{DD_{-}} \le 5.5V$ $1.71V \le V_{DD_{-}} \le 5.5V$			1.5	
Channel-to-Channel (Same Direction)	t <sub>SCSHL</sub>	1.71V ≤ V <sub>DD</sub>				1.5	ns

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Dynamic Characteristics MAX1443\_C/F/S/V (continued)**

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 3)$ 

PARAMETER	SYMBOL	(	CONDITIONS		ТҮР	MAX	UNITS	
		4.5V ≤ V <sub>DD</sub> _	≤ 5.5V			2.9		
	4	$3.0V \le V_{DD} \le 3.6V$				3.4	1	
	<sup>t</sup> SCOLH	2.25V ≤ V <sub>DD</sub>	$2.25V \le V_{DD} \le 2.75V$			4.9		
Propagation Delay Skew Channel-to-Channel		1.71V ≤ V <sub>DD</sub>	_≤ 1.89V			10.2		
(Opposite Direction)		4.5V ≤ V <sub>DD</sub> _	≤ 5.5V			3.2	ns	
	+	3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			3.8		
	t <sub>SCOHL</sub>	2.25V ≤ V <sub>DD</sub>	_≤ 2.75V			5.3		
		1.71V ≤ V <sub>DD</sub>	_≤ 1.89V			10.9		
Peak Eye Diagram Jitter	T <sub>JIT(PK)</sub>	200Mbps			90		ps	
Clock Jitter RMS	T <sub>JCLK(RMS)</sub>	500kHz Clock	Input, Rising/Falling Edges		6.5		ps	
		$4.5V \le V_{DD_{-}} \le 5.5V$				1.6		
Pico Timo (Figuro 1)	<b>t</b> _	$3.0V \le V_{DD} \le 3.6V$				2.2 ns		
Rise Time ( <u>Figure 1</u> )	t <sub>R</sub>	$2.25V \le V_{DD} \le 2.75V$				3		
		1.71V ≤ V <sub>DD</sub> ≤ 1.89V				4.5		
		$4.5V \le V_{DD}$	≤ 5.5V			1.4		
Foll Time (Figure 1)	<b>t</b> _	$3.0V \le V_{DD} \le 3.6V$				2	ns	
Fall Time ( <u>Figure 1</u> )	t <sub>F</sub>	$2.25V \le V_{DD_{-}} \le 2.75V$				2.8		
		1.71V ≤ V <sub>DD</sub>	_≤ 1.89V			5.1		
		ENA to	$4.5V \le V_{DD} \le 5.5V$			3.5		
Enable to Data Valid	t	OUT_, ENB to	$3.0V \le V_{DD} \le 3.6V$			5.8	ne	
	t <sub>EN</sub>	OUT_,	$2.25V \le V_{DD} \le 2.75V$			9.3	ns	
		C <sub>L</sub> = 15pF	$1.71V \le V_{DD} \le 1.89V$			17.4	1	
		ENA to	$4.5V \le V_{DD} \le 5.5V$			6.4		
Enable to Tristate	+	OUT_, ENB to	$3.0V \le V_{DD} \le 3.6V$			9.2	- ns	
	t <sub>TRI</sub>	OUT_,	$2.25V \le V_{DD} \le 2.75V$			12.8		
		C <sub>L</sub> = 15pF	$1.71V \le V_{DD} \le 1.89V$			19.4	]	

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### Dynamic Characteristics MAX1443\_B/E/R/U

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15p\text{F}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}) (Note 3)$ 

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Common-Mode Transient Immunity	СМТІ	IN_ = GND_	or V <sub>DD_</sub> (Note 4)		50	·	kV/µs
Maximum Data Rate	DR <sub>MAX</sub>						Mbps
Minimum Pulse Width	PW <sub>MIN</sub>	IN_ to OUT_				40	ns
Glitch Rejection		IN_ to OUT_		10	17	29	ns
			$4.5V \le V_{DD} \le 5.5V$	17.4	23.9	32.5	
	t	IN_to OUT_,	$3.0V \le V_{DD} \le 3.6V$	17.6	24.4	33.7	
	t <sub>PLH</sub> OUT_, C <sub>L</sub> = 15pF	$2.25 \text{V} \leq \text{V}_{\text{DD}} \leq 2.75 \text{V}$	18.3	25.8	36.7		
Propagation Delay			$1.71V \le V_{DD} \le 1.89V$	20.7	29.6	43.5	ns
(Figure 1)		$4.5V \le V_{DD} \le 5.5V$	16.9	23.4	33.6	113	
	tou	t <sub>PHI</sub> IN_to	$3.0V \le V_{DD} \le 3.6V$	17.2	24.2	35.1	
	C <sub>L</sub> = 1	CUT_, C <sub>L</sub> = 15pF	$2.25V \le V_{DD} \le 2.75V$	17.8	25.4	38.2	
			1.71V ≤ V <sub>DD</sub> _ ≤ 1.89V	19.8	29.3	45.8	
Pulse Width Distortion	PWD	t <sub>PLH</sub> -t <sub>PHL</sub>			0.4	4	ns
		4.5V ≤ V <sub>DD</sub> _	$4.5V \le V_{DD} \le 5.5V$			15.1	
	t <sub>SPLH</sub>	3.0V ≤ V <sub>DD</sub> _				15	
		2.25V ≤ V <sub>DD</sub>				15.4	
Propagation Delay Skew		1.71V ≤ V <sub>DD</sub>	1.71V ≤ V <sub>DD</sub> _ ≤ 1.89V			20.5	ns
Part-to-Part (Same Channel)		$4.5V \le V_{DD} \le 5.5V$				13.9	
	t <sub>SPHL</sub>	$3.0V \le V_{DD} \le 3.6V$				14.2	
	SPAL	2.25V ≤ V <sub>DD</sub>	_≤2.75V			16	
		1.71V ≤ V <sub>DD</sub>				21.8	
Propagation Delay Skew Channel-to-Channel	t <sub>SCSLH</sub>	1.71V ≤ V <sub>DD</sub>	_≤ 5.5V			2	ns
(Same Direction)	tSCSHL	1.71V ≤ V <sub>DD</sub>	≤ 5.5V			2	115
		4.5V ≤ V <sub>DD</sub> _	≤ 5.5V			13.9	
		3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			13.7	1
Propagation Delay Skew Channel-to-Channel	<sup>t</sup> SCOLH	2.25V ≤ V <sub>DD</sub>	_≤2.75V			14.2	]
		$1.71V \le V_{DD} \le 1.89V$				19.4	ns
(Opposite Direction)		$4.5V \le V_{DD}$	≤ 5.5V			13	113
	+-	3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			12.9	
	tSCOHL	2.25V ≤ V <sub>DD</sub>	_≤2.75V			14.4	1
		1.71V ≤ V <sub>DD</sub>	≤ 1.89V			20.1	

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Dynamic Characteristics MAX1443\_B/E/R/U (continued)**

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15pF, T_A = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C, \text{ unless otherwise noted.}$  (Note 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Peak Eye Diagram Jitter	T <sub>JIT(PK)</sub>	25Mbps			250		ps
		4.5V ≤ V <sub>DD</sub> _	≤ 5.5V			1.6	
	+	3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			2.2	
Rise Time ( <u>Figure 1</u> )	t <sub>R</sub>	2.25V ≤ V <sub>DD</sub>	≤ 2.75V			3	ns
		1.71V ≤ V <sub>DD</sub>	_≤ 1.89V			4.5	
		4.5V ≤ V <sub>DD</sub> _	≤ 5.5V			1.4	
Foll Time (Figure 1)	te –	3.0V ≤ V <sub>DD</sub> _	≤ 3.6V			2	
Fall Time (Figure 1)		$2.25V \le V_{DD_{-}} \le 2.75V$				2.8	ns
		1.71V ≤ V <sub>DD</sub> ≤ 1.89V				5.1	]
		ENA to	$4.5V \le V_{DD} \le 5.5V$			3.5	3.5
Enable to Data Valid	+	OUT_,	$3.0V \le V_{DD} \le 3.6V$			5.8	
	t <sub>EN</sub>	ENB to OUT_,	$2.25V \le V_{DD} \le 2.75V$			9.3	ns
		C <sub>L</sub> = 15pF	$1.71V \le V_{DD} \le 1.89V$			17.4	
	ENA to	ENA to	$4.5V \le V_{DD} \le 5.5V$			6.4	
Enable to Tristate		OUT_,	$3.0V \le V_{DD} \le 3.6V$			9.2	1
	trri	ENB to OUT_,	2.25V ≤ V <sub>DD</sub> _ ≤ 2.75V			12.8	ns
		C <sub>L</sub> = 15pF	1.71V ≤ V <sub>DD</sub> _ ≤ 1.89V			19.4	

Note 1: All devices are 100% production tested at  $T_A = +25^{\circ}C$ . Specifications over temperature are guaranteed by design.

Note 2: Not production tested. Guaranteed by design and characterization,

Note 3: All currents into the device are positive. All currents out of the device are negative. All voltages are referenced to their respective ground (GNDA or GNDB), unless otherwise noted.

**Note 4:** CMTI is the maximum sustainable common-mode voltage slew rate while maintaining the correct output. CMTI applies to both rising and falling common-mode voltage edges. Tested with the transient generator connected between GNDA and GNDB (V<sub>CM</sub> = 1000V).

#### **ESD Protection**

PARAMETER	SYMBOL	CONDITIONS MIN TYP MAX		MAX	UNITS	
ESD		Human Body Model, All Pins		±4		kV

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

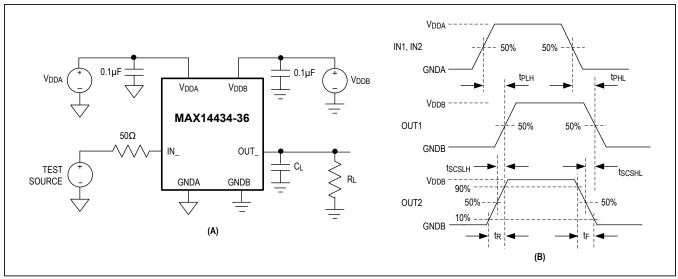


Figure 1. Test Circuit (A) and Timing Diagram (B)

#### **Safety Regulatory Approvals**

UL

The MAX14434–MAX14436 are certified under UL1577. For more details, refer to File E351759.

Rated up to  $5000V_{RMS}$  isolation voltage for single protection.

cUL (Equivalent to CSA notice 5A)

The MAX14434–MAX14436 are certified up to 5000V<sub>RMS</sub> for single protection. For more details, refer to File E351759.

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Table 1. Insulation Characteristics**

PARAMETER	SYMBOL	CONDITIONS	VALUE	UNITS	
Partial Discharge Test Voltage	V <sub>PR</sub>	Method B1 = V <sub>IORM</sub> x 1.875 (t = 1s, partial discharge < 5pC)	2250	VP	
Maximum Repetitive Peak Isolation Voltage	VIORM	(Note 5)	1200	VP	
Maximum Working Isolation Voltage	V <sub>IOWM</sub>	Continuous RMS voltage (Note 5)	848	V <sub>RMS</sub>	
Maximum Transient Isolation Voltage	V <sub>IOTM</sub>	t = 1s (Note 5)	8400	V <sub>P</sub>	
Maximum Withstand Isolation Voltage	V <sub>ISO</sub>	f <sub>SW</sub> = 60Hz, duration = 60s (Note 5, 6)	5000	V <sub>RMS</sub>	
Maximum Surge Isolation Voltage	V <sub>IOSM</sub>	Basic Insulation, 1.2/50µs pulse per IEC 61000-4-5 (Note 5, 8)	10	kV	
		V <sub>IO</sub> = 500V, T <sub>A</sub> = 25°C	> 10 <sup>12</sup>		
Insulation Resistance	R <sub>IO</sub>	$V_{IO} = 500V, 100^{\circ}C \le T_A \le 125^{\circ}C$	> 10 <sup>11</sup>	Ω	
		V <sub>IO</sub> = 500V at T <sub>S</sub> = 150°C	> 10 <sup>9</sup>		
Barrier Capacitance Side A to Side B	C <sub>IO</sub>	f <sub>SW</sub> = 1MHz (Note 7)	2	pF	
Minimum Creepage Distance	CPG		8	mm	
Minimum Clearance Distance	CLR		8	mm	
Internal Clearance		Distance through insulation	0.015	mm	
Comparative Tracking Index	СТІ	Material Group I (IEC 60112)	>600		
Climate Category			40/125/21		
Pollution Degree (DIN VDE 0110, Table 1)			2		

**Note 5:**  $V_{ISO}$ ,  $V_{IOTM}$ ,  $V_{IOSM}$ ,  $V_{IOWM}$ , and  $V_{IORM}$  are defined by the IEC 60747-5-5 standard. **Note 6:** Product is qualified at  $V_{ISO}$  for 60s and 100% production tested at 120% of  $V_{ISO}$  for 1s.

Note 7: Capacitance is measured with all pins on field-side and logic-side tied together.

Note 8: Devices are immersed in oil during surge characterization.

## Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Safety Limits**

Damage to the IC can result in a low-resistance path to ground or to the supply and, without current limiting, the MAX14434–MAX14436 could dissipate excessive amounts of power. Excessive power dissipation can damage the die and result in damage to the isolation barrier, potentially causing downstream issues. <u>Table 2</u> shows the safety limits for the MAX14434–MAX14436.

The maximum safety temperature (T<sub>S</sub>) for the device is the 150°C maximum junction temperature specified in the <u>Absolute Maximum Ratings</u>. The power dissipation (P<sub>D</sub>) and junction-to-ambient thermal impedance ( $\theta_{JA}$ ) determine the junction temperature. Thermal impedance values ( $\theta_{JA}$  and  $\theta_{JC}$ ) are available in the <u>Package</u> <u>Information</u> section of the datasheet and power dissipation calculations are discussed in the <u>Calculating Power</u> <u>Dissipation</u> section. Calculate the junction temperature (T<sub>J</sub>) as:

#### $T_J = T_A + (P_D \times \theta_{JA})$

Figure 2 and Figure 3 show the thermal derating curves for the safety power limiting of the devices and the safety current limiting of the devices. Ensure that the junction temperature does not exceed  $150^{\circ}$ C.

#### Table 2. Safety Limiting Values for the MAX14434–MAX14436

PARAMETER	SYMBOL	TEST CONDITIONS	MAX	UNITS
Safety Current on Any Pin (No Damage to Isolation Barrier)	I <sub>S</sub>	T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C	300	mA
Total Safety Power Dissipation	P <sub>S</sub>	T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C	1760	mW
Maximum Safety Temperature	Τ <sub>S</sub>		150	°C

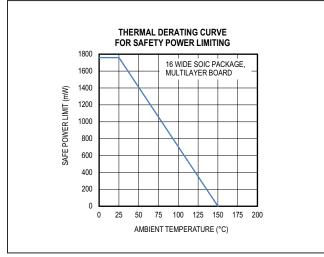


Figure 2. Thermal Derating Curve for Safety Power Limiting

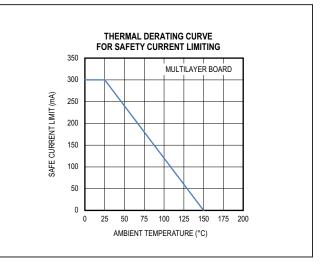
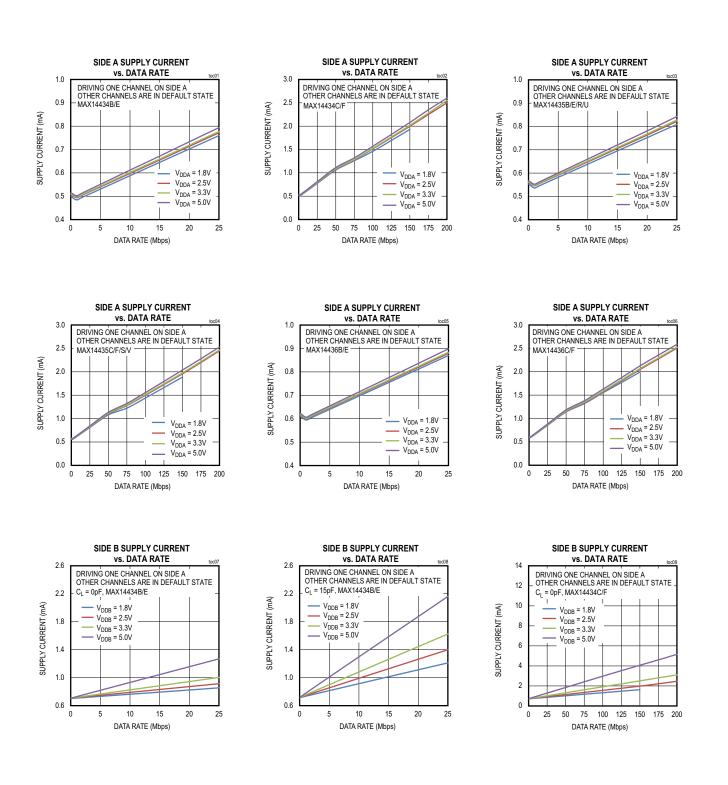


Figure 3. Thermal Derating Curve for Safety Current Limiting

## Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Typical Operating Characteristics**

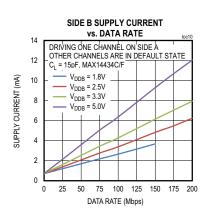
 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C, unless otherwise noted.)$ 

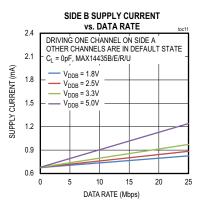


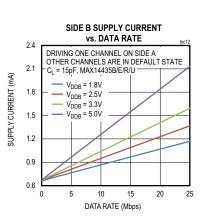
# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

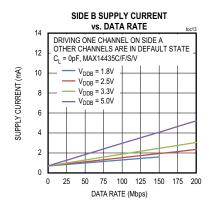
#### **Typical Operating Characteristics (continued)**

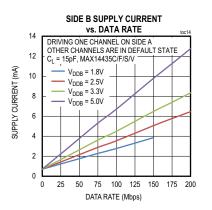
 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C$ , unless otherwise noted.)

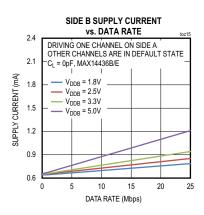


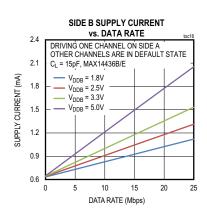


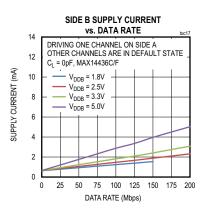


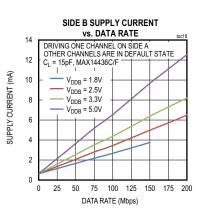








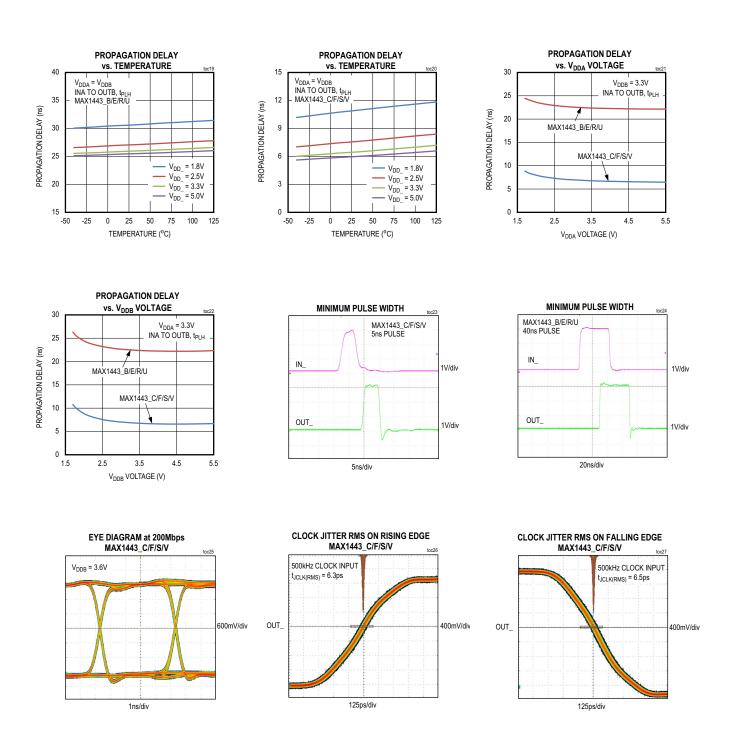




# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

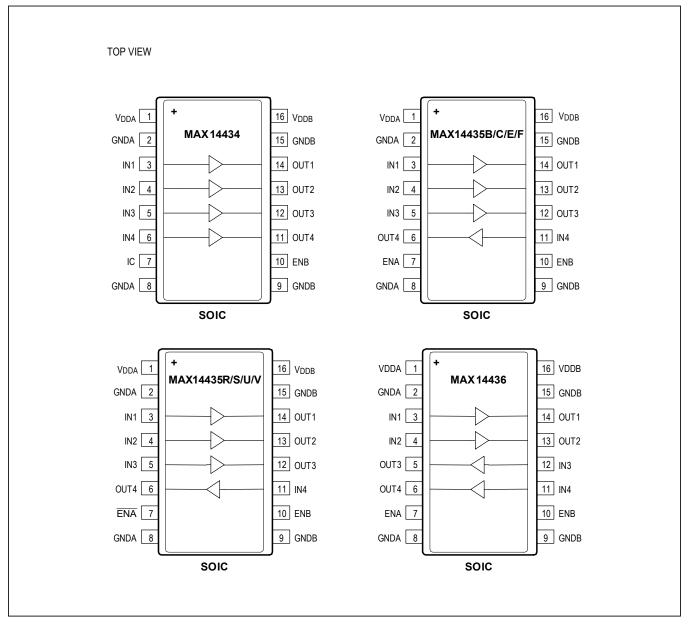
#### **Typical Operating Characteristics (continued)**

 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C, unless otherwise noted.)$ 



# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Pin Configurations**

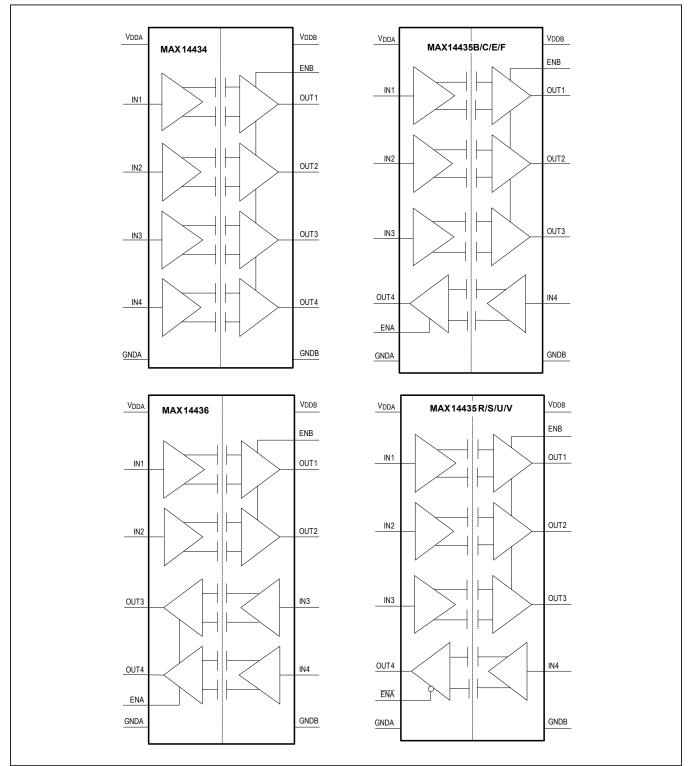


# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

## **Pin Description**

		P	N		
NAME	MAX14434	MAX14435B/C/E/F	MAX14435R/S/U/V	MAX14436	FUNCTION
V <sub>DDA</sub>	1	1	1	1	Power Supply. Bypass V <sub>DDA</sub> with a 0.1µF ceramic capacitor as close as possible to the pin.
GNDA	2, 8	2, 8	2, 8	2, 8	Ground Reference for Side A
IN1	3	3	3	3	Logic Input 1 on Side A, corresponds to Logic Output 1 on Side B
IN2	4	4	4	4	Logic Input 2 on Side A, corresponds to Logic Output 2 on Side B
IN3	5	5	5	12	Logic Input 3 on Side A or B, corresponds to Logic Output 3 on Side B or A
IN4	6	11	11	11	Logic Input 4 on Side A or B, corresponds to Logic Output 4 on Side B or A
I.C.	7	_	_	_	Internally Connected. Leave unconnected or connect to GNDA or V <sub>DDA</sub> .
ENA	_	7	_	7	Active-High Enable for Side A. ENA has an internal 5µA pullup to V <sub>DDA</sub> .
ENA	_	_	7	_	Active-Low Enable for Side A. $\overline{\text{ENA}}$ has an internal 5µA pullup to V <sub>DDA</sub>
OUT1	14	14	14	14	Logic Output 1 on Side B
OUT2	13	13	13	13	Logic Output 2 on Side B
OUT3	12	12	12	5	Logic Output 3 on Side A or Side B
OUT4	11	6	6	6	Logic Output 4 on Side A or Side B
ENB	10	10	10	10	Active-High Enable for Side B. ENB has an internal $5\mu$ A pullup to V <sub>DDB</sub> .
GNDB	9, 15	9, 15	9, 15	9, 15	Ground Reference for Side B
V <sub>DDB</sub>	16	16	16	16	Power Supply. Bypass $V_{DDB}$ with a 0.1µF ceramic capacitor as close as possible to the pin.

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators



## **Functional Diagram**

#### **Detailed Description**

The MAX14434–MAX14436 are a family of 4-channel digital isolators. The MAX14434–MAX14436 have an isolation rating of  $5kV_{RMS}$ . The MAX14434–MAX14436 family offers all three possible unidirectional channel configurations to accommodate any 4-channel design, including SPI, RS-232, RS-485, and digital I/O applications. For applications requiring bidirectional channels, such as I<sup>2</sup>C, see the MAX14933 and MAX14937.

The MAX14434 features four channels transferring digital signals in one direction for applications such as isolated digital I/O. The MAX14435 has three channels transmitting data in one direction and one channel transmitting in the opposite direction, making it ideal for applications such as isolated SPI and RS-485 communication. The MAX14436 provides further design flexibility with two channels in each direction for isolated RS-232 or other applications.

Devices are available in the 16-pin wide-body SOIC package and are rated for up to 5kV<sub>RMS</sub>. This family of digital isolators offers low-power operation, high electromagnetic interference (EMI) immunity, and stable temperature performance through Maxim's proprietary process technology. The devices isolate different ground domains and block high-voltage/high-current transients from sensitive or human interface circuitry.

Devices are available with a maximum data rate of either 25Mbps (B/E/R/U versions) or 200Mbps (C/F/S/V versions). Each device can be ordered with default-high or default-low outputs. The default is the state the output assumes when the input is not powered or if the input is open circuit. The devices have two supply inputs ( $V_{DDA}$  and  $V_{DDB}$ ) that independently set the logic levels on either side of the device.  $V_{DDA}$  and  $V_{DDB}$  are referenced to GNDA and GNDB, respectively. The MAX14434–MAX14436 family also features a refresh circuit to ensure output accuracy when an input remains in the same state indefinitely.

#### **Digital Isolation**

The MAX14434–MAX14436 family provides galvanic isolation for digital signals that are transmitted between two ground domains. The devices withstand differences of up to  $5kV_{RMS}$  for up to 60 seconds, and up to  $1200V_{PEAK}$ of continuous isolation.

#### Level-Shifting

The wide supply voltage range of both V<sub>DDA</sub> and V<sub>DDB</sub> allows the MAX14434–MAX14436 family to be used for level translation in addition to isolation. V<sub>DDA</sub> and V<sub>DDB</sub> can be independently set to any voltage from 1.71V to 5.5V. The supply voltage sets the logic level on the corresponding side of the isolator.

#### **Unidirectional Channels**

Each channel of the MAX14434–MAX14436 is unidirectional; it only passes data in one direction, as indicated in the functional diagram. Each device features four unidirectional channels that operate independently with guaranteed data rates from DC up to 25Mbps (B/E/R/U versions), or from DC to 200Mbps (C/F/S/V versions). The output driver of each channel is push-pull, eliminating the need for pullup resistors. The outputs are able to drive both TTL and CMOS logic inputs.

#### Startup and Undervoltage-Lockout

The V<sub>DDA</sub> and V<sub>DDB</sub> supplies are both internally monitored for undervoltage conditions. Undervoltage events can occur during power-up, power-down, or during normal operation due to a sagging supply voltage. When an undervoltage condition is detected on either supply while the outputs are enabled, all outputs go to their default states regardless of the state of the inputs (<u>Table 3</u> and <u>Table 4</u>). Figure 4 through Figure 7 show the behavior of the outputs during power-up and power-down.

		-				
V <sub>IN</sub> _	V <sub>DDA</sub>	V <sub>DDB</sub>	ENA	ENB	V <sub>OUTA</sub>	V <sub>OUTB</sub>
4			1	1	1	1
I	Powered	Powered	0	0	Hi-Z	Hi-Z
0	Doworod	Powered	1	1	0	0
0	Powered		0	0	Hi-Z	Hi-Z
v	Lindonvoltago	Powered	1	1	Default	Default
~	X Undervoltage		0	0	Hi-Z	Hi-Z
V	Doworod	Undervoltage	1	1	Default	Default
Х	Powered		0	0	Hi-Z	Hi-Z

#### Table 3. MAX1443 B/C/E/F Output Behavior During Undervoltage Conditions

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### Table 4. MAX14435R/S/U/V Output Behavior During Undervoltage Conditions

V <sub>IN</sub> _	V <sub>DDA</sub>	V <sub>DDB</sub>	ENA	ENB	V <sub>OUTA</sub>	V <sub>OUTB</sub>
4				1	1	1
1	Powered	Powered	1	0	Hi-Z	Hi-Z
0	Davard	Powered	0	1	0	0
0	Powered		1	0	Hi-Z	Hi-Z
×	Undervoltage	Powered	0	1	Default	Default
X			1	0	Hi-Z	Hi-Z
×	Devuered		0	1	Default	Default
Х	Powered	Undervoltage	1	0	Hi-Z	Hi-Z

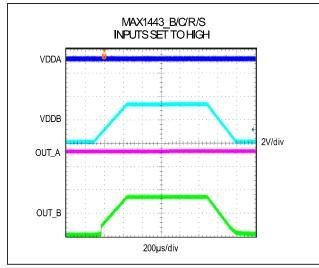


Figure 4. Undervoltage Lockout Behavior (MAX1443\_B/C/R/S High)

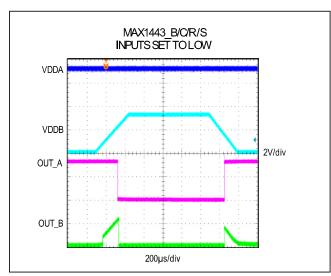


Figure 6. Undervoltage Lockout Behavior (MAX1443\_B/C/R/S Low)

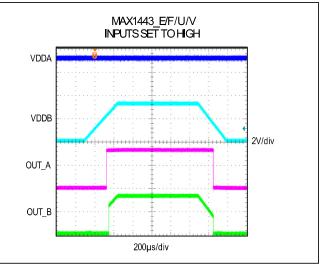


Figure 5. Undervoltage Lockout Behavior (MAX1443\_E/F/U/V High)

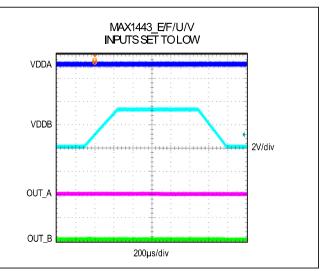


Figure 7. Undervoltage Lockout Behavior (MAX1443\_E/F/U/V Low)

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Applications Information**

#### **Power-Supply Sequencing**

The MAX14434–MAX14436 do not require special power supply sequencing. The logic levels are set independently on either side by  $V_{DDA}$  and  $V_{DDB}$ . Each supply can be present over the entire specified range regardless of the level or presence of the other supply.

#### **Power-Supply Decoupling**

To reduce ripple and the chance of introducing data errors, bypass  $V_{DDA}$  and  $V_{DDB}$  with 0.1µF low-ESR ceramic capacitors to GNDA and GNDB, respectively. Place the bypass capacitors as close to the power supply input pins as possible.

# Layout Considerations

The PCB designer should follow some critical recommendations in order to get the best performance from the design.

- Keep the input/output traces as short as possible. To keep signal paths low-inductance, avoid using vias.
- Have a solid ground plane underneath the highspeed signal layer.
- Keep the area underneath the MAX14434–MAX14436 free from ground and signal planes. Any galvanic or metallic connection between the field-side and logic-side defeats the isolation.

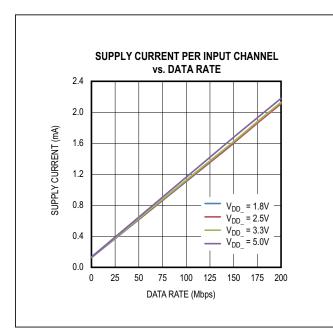


Figure 8. Supply Current Per Input Channel (Estimated)

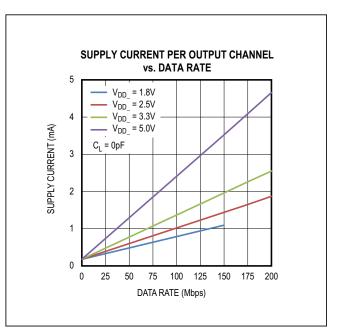


Figure 9. Supply Current Per Output Channel (Estimated)

## Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Calculating Power Dissipation**

The required current for a given supply ( $V_{DDA}$  or  $V_{DDB}$ ) can be estimated by summing the current required for each channel. The supply current for a channel depends on whether the channel is an input or an output, the channel's data rate, and the capacitive or resistive load if it is an output. The typical current for an input or output at any data rate can be estimated from the graphs in Figure 8 and Figure 9. Please note the data in Figure 8 and Figure 9 are extrapolated from the supply current measurements in a typical operating condition.

The total current for a single channel is the sum of the "no load" current (shown in <u>Figure 8</u> and <u>Figure 9</u>) which is a function of Voltage and Data Rate, and the "load current," which depends on the type of load. Current into a capacitive load is a function of the load capacitance, the switching frequency, and the supply voltage.

$$I_{CL} = C_L \times f_{SW} \times V_{DD}$$

where

 $I_{CI}$  is the current required to drive the capacitive load.

C<sub>L</sub> is the load capacitance on the isolator's output pin.

 $f_{SW}$  is the switching frequency (bits per second / 2).

V<sub>DD</sub> is the supply voltage on the output side of the isolator.

Current into a resistive load depends on the load resistance, the supply voltage and the average duty cycle of the data waveform. The DC load current can be conservatively estimated by assuming the output is always high.

$$I_{RL} = V_{DD} \div R_L$$

where

 $I_{RL}$  is the current required to drive the resistive load.

 $V_{DD}$  is the supply voltage on the output side of the isolator.  $R_L$  is the load resistance on the isolator's output pin.

**Example** (shown in Figure 10): A MAX14435F is operating with V<sub>DDA</sub> = 2.5V, V<sub>DDB</sub> = 3.3V, channel 1 operating at 20Mbps with a 10pF capacitive load, channel 2 held high with a 10k $\Omega$  resistive load, and channel 4 operating at 100Mbps with a 15pF capacitive load. Channel 3 is not in use and the resistive load is negligible since the isolator is driving a CMOS input. Refer to Table 5 and Table 6 for V<sub>DDA</sub> and V<sub>DDB</sub> supply current calculation worksheets.

#### V<sub>DDA</sub> must supply:

- Channel 1 is an input channel operating at 2.5V and 20Mbps, consuming 0.33mA, estimated from Figure 8.
- Channel 2 and 3 are input channels operating at 2.5V with DC signal, consuming 0.13mA, estimated from Figure 8.
- Channel 4 is an output channel operating at 2.5V and 100Mbps, consuming 1.02mA, estimated from Figure 9.
- I<sub>CL</sub> on channel 4 for 15pF capacitor at 2.5V and 100Mbps is 1.875mA.

# Total current for side A = 0.33 + 0.13 × 2 + 1.02 + 1.875 = 3.485mA, typical

#### V<sub>DDB</sub> must supply:

- Channel 1 is an output channel operating at 3.3V and 20Mbps, consuming 0.42mA, estimated from Figure 9.
- Channel 2 and 3 are output channels operating at 3.3V with DC signal, consuming 0.18mA, estimated from Figure 9.
- Channel 4 is an input channel operating at 3.3V and 100Mbps, consuming 1.13mA, estimated from Figure 8.
- I<sub>CL</sub> on channel 1 for 10pF capacitor at 3.3V and 20Mbps is 0.33mA.
- I<sub>RL</sub> on channel 2 for 10kΩ resistor held at 3.3V is 0.33mA.

Total current for side B = 0.42 + 0.18 × 2 + 1.13 + 0.33 + 0.33 = 2.57mA, typical

#### Table 5. Side A Supply Current Calculation Worksheet

SIDE A		V <sub>DDA</sub> = 2.5V							
Channel	IN/ OUT	Data Rate (Mbps)	Load Type	Load	"No Load" Current (mA)	Load Current (mA)			
1	IN	20			0.33				
2	IN	0			0.13				
3	IN	0			0.13				
4	OUT	100	Capacitive	15pF	1.02	2.5V x 50MHz x 15pF = 1.875mA			
Total: 3.485mA									

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

SIDE B		V <sub>DDB</sub> = 3.3V								
Channel	IN/ OUT	Data Rate (Mbps)	Load Type	Load	"No Load" Current (mA)	Load Current (mA)				
1	OUT	20	Capacitive	10pF	0.42	3.3V x 10MHz x 10pF = 0.33mA				
2	OUT	0	Resistive	10kΩ	0.18	3.3V / 10kΩ = 0.33mA				
3	OUT	0			0.18					
4	IN	100			1.13					
	· · ·			Total: 2.57m	۱A					

#### Table 6. Side B Supply Current Calculation Worksheet

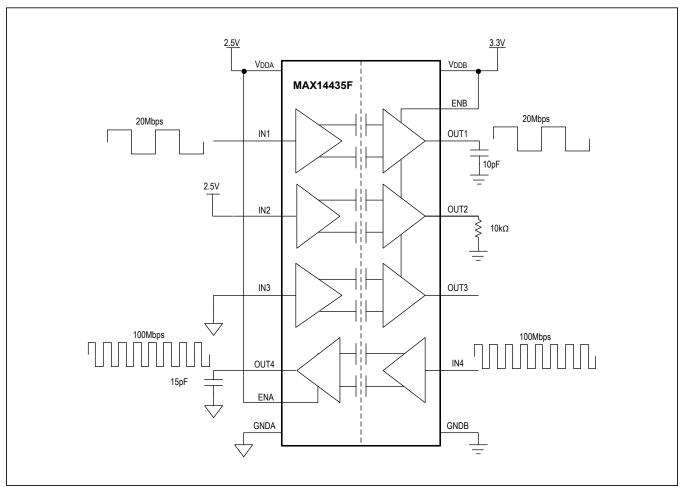
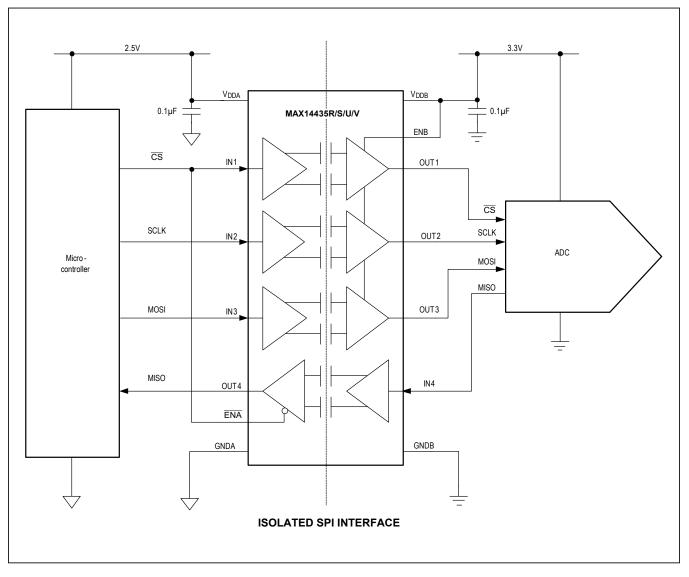


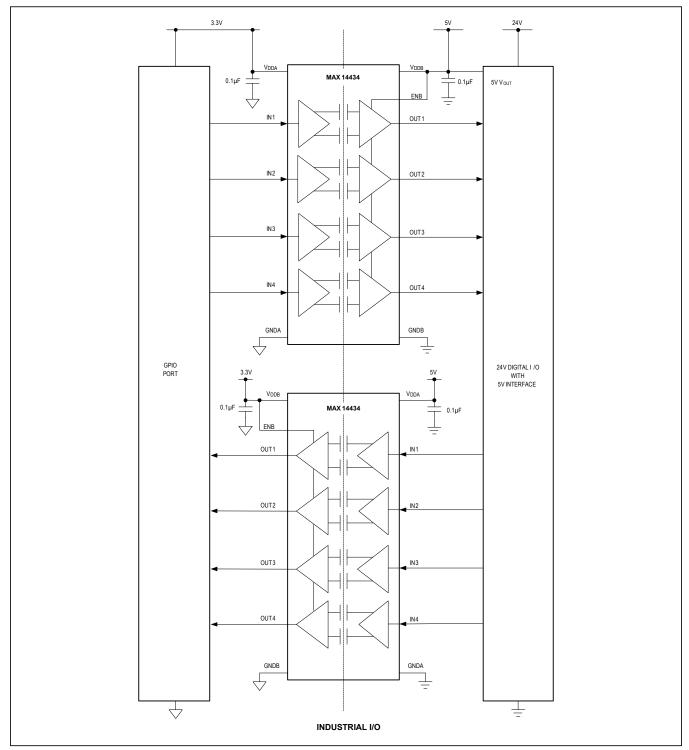
Figure 10. Example Circuit for Supply Current Calculation

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

## **Typical Application Circuits**

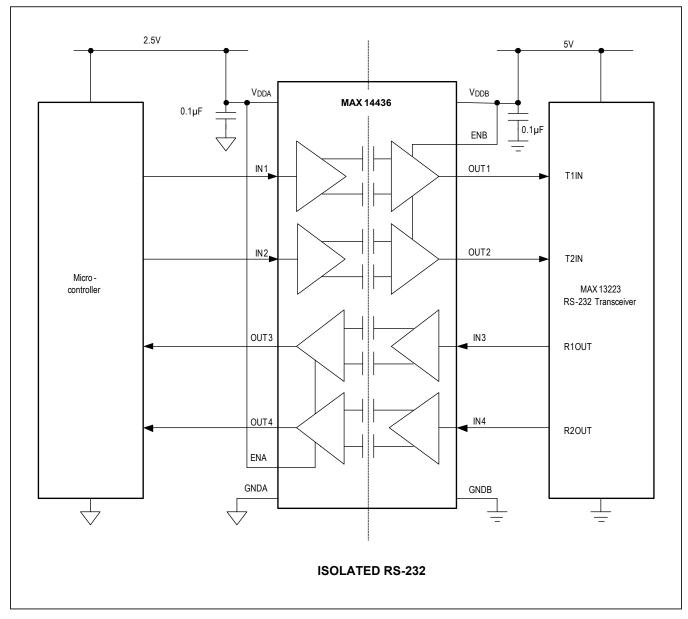


# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators



# **Typical Application Circuits (continued)**

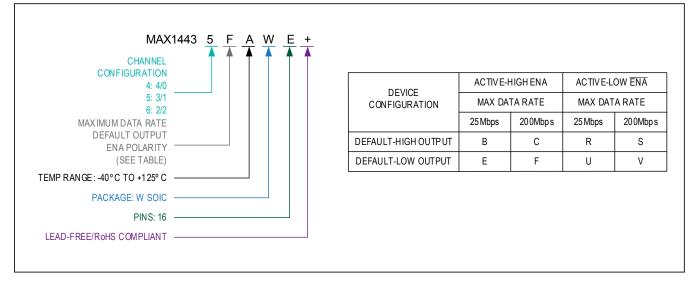
# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators



## **Typical Application Circuits (continued)**

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Product Selector Guide**



#### **Ordering Information**

PART	CHANNEL CONFIGU- RATION	DATA RATE (Mbps)	DEFAULT OUTPUT	ENA Polarity	ISOLATION VOLTAGE (kV <sub>RMS</sub> )	TEMP RANGE (°C)	PIN-PACKAGE
MAX14434BAWE+*	4/0	25	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14434CAWE+*	4/0	200	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14434EAWE+	4/0	25	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14434FAWE+	4/0	200	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435BAWE+*	3/1	25	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435CAWE+*	3/1	200	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435EAWE+*	3/1	25	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435FAWE+	3/1	200	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14435RAWE+*	3/1	25	Default High	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14435SAWE+*	3/1	200	Default High	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14435UAWE+*	3/1	25	Default Low	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14435VAWE+*	3/1	200	Default Low	Active-Low	5.0	-40 to +125	16 Wide SOIC
MAX14436BAWE+*	2/2	25	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14436CAWE+*	2/2	200	Default High	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14436EAWE+*	2/2	25	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC
MAX14436FAWE+	2/2	200	Default Low	Active-High	5.0	-40 to +125	16 Wide SOIC

\*Future Product—Contact Maxim for availability.

+Denotes a lead(Pb)-free/RoHS-compliant package.

#### **Chip Information**

PROCESS: BICMOS

# Four-Channel, Fast, Low-Power, 5kV<sub>RMS</sub> Digital Isolators

#### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/17	Initial release	—
1	8/17	Updated Insulation Characteristics table	10
2	1/18	Updated Ordering Information table	25
3	1/19	Removed future product designation from MAX14434FAWE+ in the Ordering Information table	24
4	2/19	Updated the Safety and Regulatory Approvals section and added the Safety and Regulatory Approvals table	1, 9
5	12/19	Removed future product designation from MAX14434EAWE+ in the Ordering Information table	25
2	11/20	Updated General Description, Dynamic Characteristics MAX1443_C/F/S/V, Dynamic Characteristics MAX1443_B/E/R/U, Safety Regulatory Approvals, Typical Operating Circuits, and Layout Considerations sections; added Safety Limits and Product Selector Guide sections; added new Figure 2–3 and renumbered subsequent figures; replaced Figure 8–9; updated Table 1; added Table 2, Table 4 and renumbered subsequent tables; added Product Selector Guide	1, 6–12, 13–15, 19–24

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